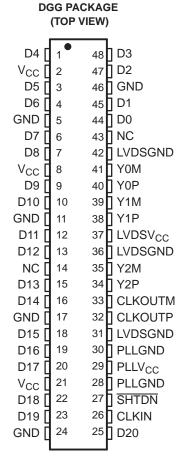


LVDS SERDES TRANSMITTER

Check for Samples: SN65LVDS95

FEATURES

- 3:21 Data Channel Compression at up to 1.428 Gigabits/s Throughput
- Suited for Point-to-Point Subsystem Communication With Very Low EMI
- 21 Data Channels Plus Clock in Low-Voltage TTL and 3 Data Channels Plus Clock Out Low-Voltage Differential
- Operates From a Single 3.3-V Supply and 250 mW (Typ)
- 5-V Tolerant Data Inputs
- 'LVDS95 Has Rising Clock Edge Triggered Inputs
- Bus Pins Tolerate 6-kV HBM ESD
- Packaged in Thin Shrink Small-Outline Package With 20 Mil Terminal Pitch
- Consumes <1 mW When Disabled
- Wide Phase-Lock Input Frequency Range 20 MHz to 68 MHz
- No External Components Required for PLL
- Inputs Meet or Exceed the Requirements of ANSI EIA/TIA-644 Standard
- Industrial Temperature Qualified T_A = -40°C to 85°C
- Replacement for the National DS90CR215



DESCRIPTION

The SN65LVDS95 LVDS serdes (serializer/deserializer) transmitter contains three 7-bit parallel-load serial-out shift registers, a 7× clock synthesizer, and four low-voltage differential signaling (LVDS) line drivers in a single integrated circuit. These functions allow 21 bits of single-ended LVTTL data to be synchronously transmitted over 4 balanced-pair conductors for receipt by a compatible receiver, such as the SN65LVDS96.

When transmitting, data bits D0 through D20 are each loaded into registers of the SN65LVDS95 on the rising edge of the input clock signal (CLKIN). The frequency of CLKIN is multiplied seven times and then used to serially unload the data registers in 7-bit slices. The three serial streams and a phase-locked clock (CLKOUT) are then output to LVDS output drivers. The frequency of CLKOUT is the same as the input clock, CLKIN.

The SN65LVDS95 requires no external components and little or no control. The data bus appears the same at the input to the transmitter and output of the receiver with data transmission transparent to the user(s). The only user intervention is the possible use of the shutdown/clear (SHTDN) active-low input to inhibit the clock and shut off the LVDS output drivers for lower power consumption. A low level on this signal clears all internal registers to a low level.

The SN65LVDS95 is characterized for operation over ambient air temperatures of -40°C to 85°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

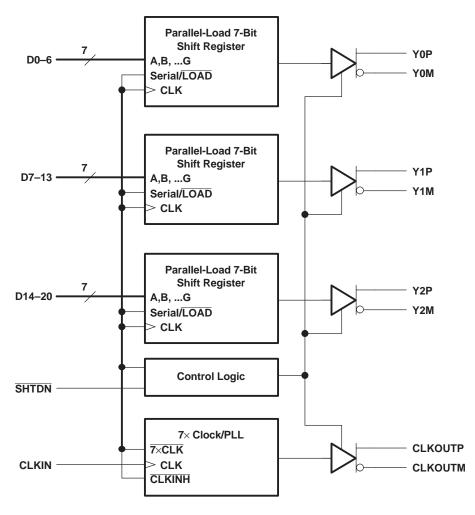




This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

FUNCTIONAL BLOCK DIAGRAM





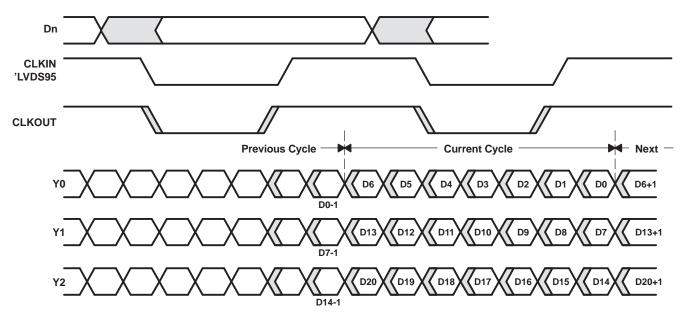
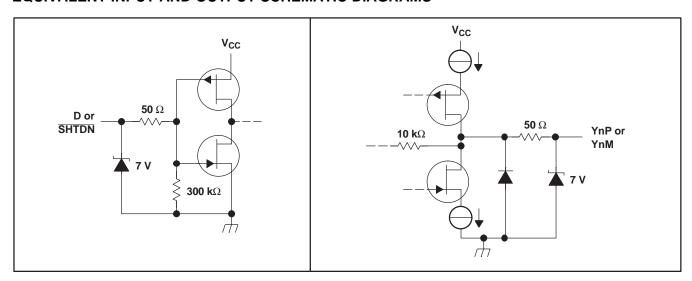


Figure 1. 'LVDS95 Load and Shift Sequences

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS





ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

			UNIT
V _{CC}	Supply voltage range ⁽²⁾		–0.5 V to 4 V
Vo	Voltage range at any output to	erminal	-0.5 V to V _{CC} + 0.5 V
V_{I}	Voltage range at any input ter	rminal	–0.5 V to 5.5 V
		Bus pins (Class 3A)	6 KV
	Electrostatic discharge (3)	Bus pins (Class 2B)	400 V
		All pins (Class 3A)	6 KV
		All pins (Class 2B)	200 V
	Continuous total power dissip	ation	See Dissipation Rating Table
T_A	Operating free-air temperature	e range	-40°C to 85°C
T _{stg}	Storage temperature range		−65°C to 150°C
	Lead temperature 1,6 mm (1/	16 inch) from case for 10 seconds	260°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C	DERATING FACTOR ⁽¹⁾	T _A = 70°C	T _A = 85°C
	POWER RATING	ABOVE T _A = 25°C	POWER RATING	POWER RATING
DGG	1316 mW	13.1 mW/°C	724 mW	526 mW

⁽¹⁾ This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
V_{CC}	Supply voltage	3	3.3	3.6	V
V_{IH}	High-level input voltage	2			V
V_{IL}	Low-level input voltage			8.0	V
Z_{L}	Differential load impedance	90		132	Ω
T_A	Operating free-air temperature	40		85	°C

⁽²⁾ All voltage values are with respect to the GND terminals.

⁽³⁾ This rating is measured using MIL-STD-883C Method, 3015.7.



ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT}	Input voltage threshold			1.4		V
V _{OD}	Differential steady-state output voltage magnitude		247		454	
$\Delta V_{OD} $	Change in the steady-state differential output voltage magnitude between opposite binary states	R_L = 100 Ω, See Figure 3			50	mV
V _{OC(SS)}	Steady-state common-mode output voltage	See Figure 3	1.125		1.37 5	V
$V_{OC(PP)}$	Peak-to-peak common-mode output voltage			80	150	mV
I _{IH}	High-level input current	$V_{IH} = V_{CC}$			20	μΑ
I _{IL}	Low-level input current	V _{IL} = 0 V			±10	μΑ
	Chart singuit autout aurona	V _{OY} = 0 V			±24	mA
I _{OS}	Short-circuit output current	V _{OD} = 0 V			±12	mA
l _{OZ}	High-impedance state output current	$V_O = 0 \text{ V to } V_{CC}$			±10	μΑ
		Disabled, all inputs at GND			280	μA
I _{CC(AVG)}	Quiescent current (average)	Enabled, R_L = 100 Ω (4 places), Worst-case pattern (see Figure 4), t_c = 15.38 ns		85	110	mA
Ci	Input capacitance			3		pF

⁽¹⁾ All typical values are V_{CC} = 3.3 V, T_A = 25°C.

TIMING REQUIREMENTS

		MIN	NOM	MAX	UNIT
t _c	Input clock period	14.7	t _c	50	ns
t _w	High-level input clock pulse width duration	0.4t _c		0.6t _c	ns
t _t	Input signal transition time			5	ns
t _{su}	Data setup time, D0 through D27 before CLKIN↑ ('95) (see Figure 2)	3			ns
t _h	Data hold time, D0 through D27 after CLKIN↑ ('95) (see Figure 2)	1.5			ns



SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

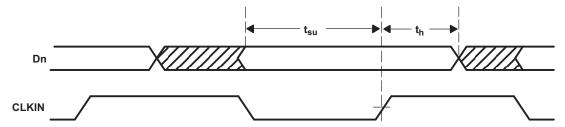
	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
t ₀	Delay time, CLKOUT serial bit position 0		-0.20	0	0.20	ns
t ₁	Delay time, CLKOUT↑ serial bit position 1		1/7t _c -0.20		1/7t _c +0.20	ns
t ₂	Delay time, CLKOUT↑ serial bit position 2		2/7t _c -0.20		2/7t _c +0.20	ns
t ₃	Delay time, CLKOUT↑ serial bit position 3	$t_c = 15.38 \text{ ns } (\pm 0.2\%),$ Input clock jitter < 50 ps ⁽²⁾ ,	3/7t _c -0.20		3/7t _c +0.20	ns
t ₄	Delay time, CLKOUT↑ serial bit position 4	See Figure 5	4/7t _c -0.20		4/7t _c +0.20	ns
t ₅	Delay time, CLKOUT↑ serial bit position 5		5/7t _c -0.20		5/7t _c +0.20	ns
t ₆	Delay time, CLKOUT↑ serial bit position 6		6/7t _c -0.20		6/7t _c +0.20	ns
t _{sk(o)}	Output skew, t_n –n/7 t_c		-0.20		0.20	ns
t ₇	Delay time, CLKIN† to CLKOUT†	t_c = 15.38 ns (±0.2%), Input clock jitter < 50 ps ⁽²⁾ , See Figure 5	4.2			ns
۸4	Output clock cycle-to-cycle jitter ⁽³⁾	t_{c} = 15.38 ns + 0.75 sin(2 π 500E3t) ±0.05 ns, See Figure 6		±80		ps
$\Delta t_{C(O)}$	Output clock cycle-to-cycle jitter	t_c = 15.38 ns + 0.75 sin(2 π 2E6t) ±0.05 ns, See Figure 6	±300			ps
t _w	High-level output clock pulse duration			$4/7 t_c$		ns
t _t	Differential output voltage transition time (t _r or t _f)	See Figure 3	260	700	1500	ps
t _{en}	Enable time, SHTDN↑ to phase lock (Yn valid)	See Figure 7		1		ms
t _{dis}	Disable time, SHTDN↓ to off-state (CLKOUT low)	See Figure 8		250		ns

All typical values are $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$. |Input clock jitter| is the magnitude of the change in the input clock period.

The output clock jitter is the change in the output clock period from one cycle to the next cycle observed over 15,000 cycles.

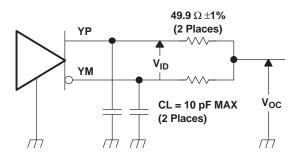


PARAMETER MEASUREMENT INFORMATION



NOTE: All input timing is defined at 1.4 V on an input signal with a 10% to 90% rise or fall time of less than 5 ns.

Figure 2. Setup and Hold Time Definition



NOTE: The lumped instrumentation capacitance for any single ended voltage measurement is less than or equal to 10 pF. When making measurements at YP or YM, the complementary output shall be similarly loaded.

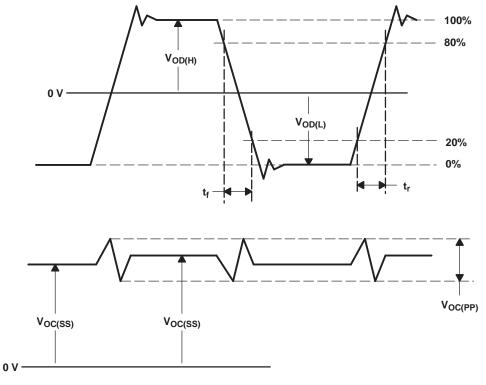
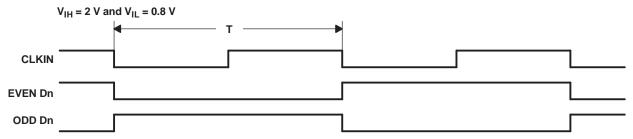


Figure 3. Test Load and Voltage Definitions for LVDS Outputs



PARAMETER MEASUREMENT INFORMATION (continued)



(1) The worst-case test pattern produces nearly the maximum switching frequency for all of the LV-TTL outputs.

Figure 4. Worst-Case Power Test Pattern

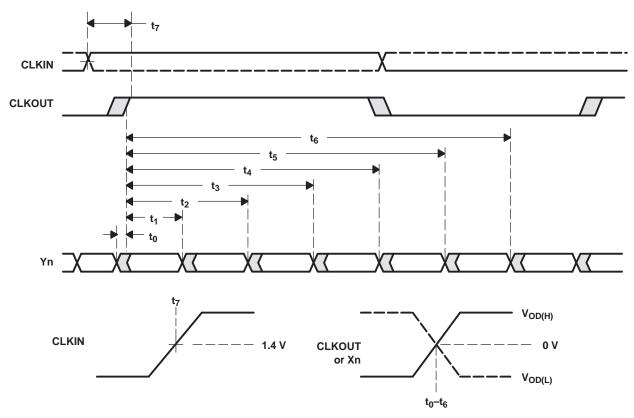


Figure 5. Timing Definitions



PARAMETER MEASUREMENT INFORMATION (continued)

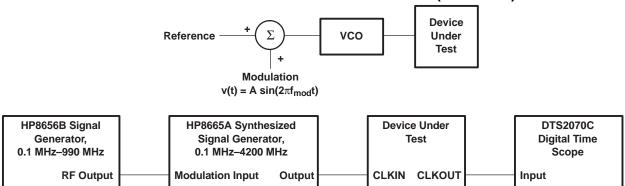


Figure 6. Clock Jitter Test Setup

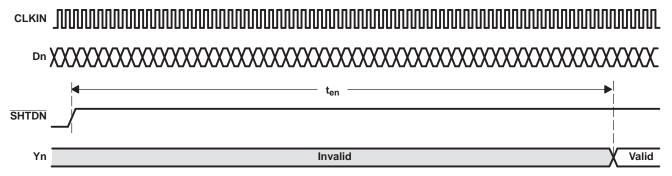


Figure 7. Enable Time Measurement Definition

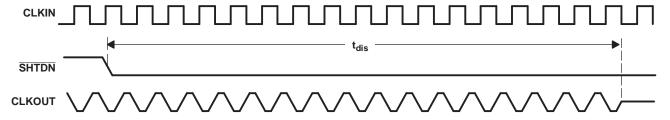
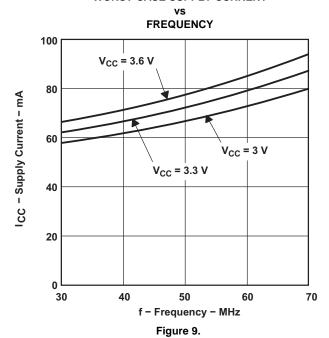


Figure 8. Disable Time Measurement Definition



TYPICAL CHARACTERISTICS

WORST-CASE SUPPLY CURRENT





APPLICATION INFORMATION

16-BIT BUS EXTENSION

In a 16-bit bus application (Figure 10), TTL data and clock coming from bus transceivers that interface the backplane bus arrive at the Tx parallel inputs of the LVDS serdes transmitter. The clock associated with the bus is also connected to the device. The on-chip PLL synchronizes this clock with the parallel data at the input. The data is then multiplexed into three different line drivers which perform the TTL to LVDS conversion. The clock is also converted to LVDS and presented to a separate driver. This synchronized LVDS data and clock at the receiver, which recovers the LVDS data and clock, performs a conversion back to TTL. Data is then demultiplexed into a parallel format. An on-chip PLL synchronizes the received clock with the parallel data, and then all are presented to the parallel output port of the receiver.

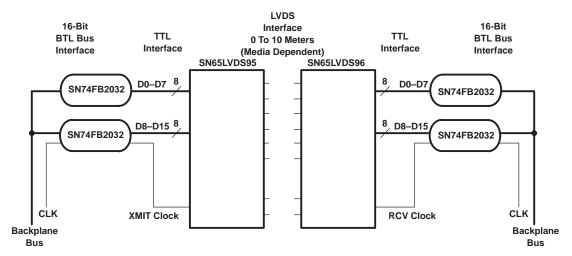


Figure 10. 16-Bit Bus Extension

16-BIT BUS EXTENSION WITH PARITY

In the previous application we did not have a checking bit that would provide assurance that the data crosses the link. If we add a parity bit to the previous example, we would have a diagram similar to the one in Figure 11. The device following the SN74FB2032 is a low cost parity generator. Each transmit-side transceiver/parity generator takes the LVTTL data from the corresponding transceiver, performs a parity calculation over the byte, and then passes the bits with its calculated parity value on the parallel input of the LVDS serdes transmitter. Again, the on-chip PLL synchronizes this transmit clock with the eighteen parallel bits (16 data + 2 parity) at the input. The synchronized LVDS data/parity and clock arrive at the receiver.

The receiver performs the conversion from LVDS to LVTTL and the transceiver/parity generator performs the parity calculations. These devices compare their corresponding input bytes with the value received on the parity bit. The transceiver/parity generator will assert its parity error output if a mismatch is detected.



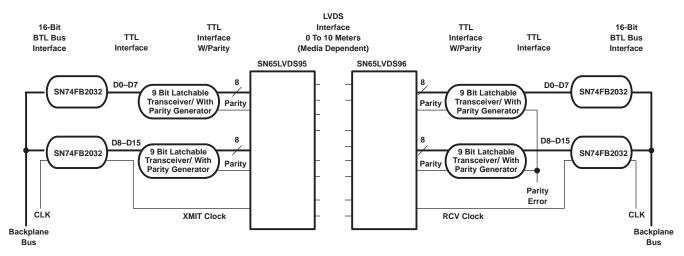


Figure 11. 16-Bit Bus Extension With Parity

LOW COST VIRTUAL BACKPLANE TRANSCEIVER

Figure 12 represents LVDS serdes in an application as a virtual backplane transceiver (VBT). The concept of a VBT can be achieved by implementing individual LVDS serdes chipsets in both directions of subsystem serialized links.

Depending on the application, the designer will face varying choices when implementing a VBT. In addition to the devices shown in Figure 12, functions such as parity and delay lines for control signals could be included. Using additional circuitry, half-duplex or full-duplex operation can be achieved by configuring the clock and control lines properly.

The designer may choose to implement an independent clock oscillator at each end of the link and then use a PLL to synchronize LVDS serdes's parallel I/O to the backplane bus. Resynchronizing FIFOs may also be required.

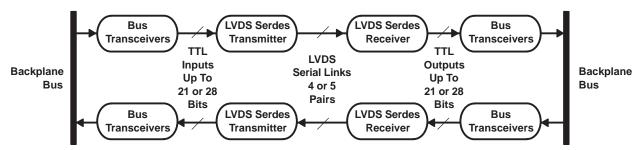


Figure 12. Virtual Backplane Transceiver

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
ONIOSI VIDOOSDOO	A - 1'	Dandontina	T000D (D00) I 40	40 TUDE		` /	` '	40.1- 05	ONIGEL VID OGE
SN65LVDS95DGG	Active	Production	TSSOP (DGG) 48	40 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SN65LVDS95
SN65LVDS95DGG.B	Active	Production	TSSOP (DGG) 48	40 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SN65LVDS95
SN65LVDS95DGGG4	Active	Production	TSSOP (DGG) 48	40 TUBE	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SN65LVDS95
SN65LVDS95DGGR	Active	Production	TSSOP (DGG) 48	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SN65LVDS95
SN65LVDS95DGGR.B	Active	Production	TSSOP (DGG) 48	2000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SN65LVDS95

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE OPTION ADDENDUM

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OTHER QUALIFIED VERSIONS OF SN65LVDS95:

Automotive: SN65LVDS95-Q1

● Enhanced Product : SN65LVDS95-EP

NOTE: Qualified Version Definitions:

• Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

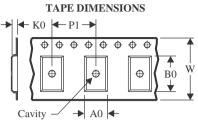
• Enhanced Product - Supports Defense, Aerospace and Medical Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

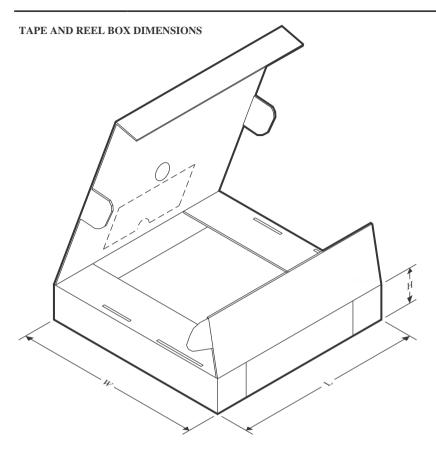


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LVDS95DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1

PACKAGE MATERIALS INFORMATION

www.ti.com 23-May-2025



*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	SN65LVDS95DGGR	TSSOP	DGG	48	2000	350.0	350.0	43.0	

PACKAGE MATERIALS INFORMATION

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TUBE

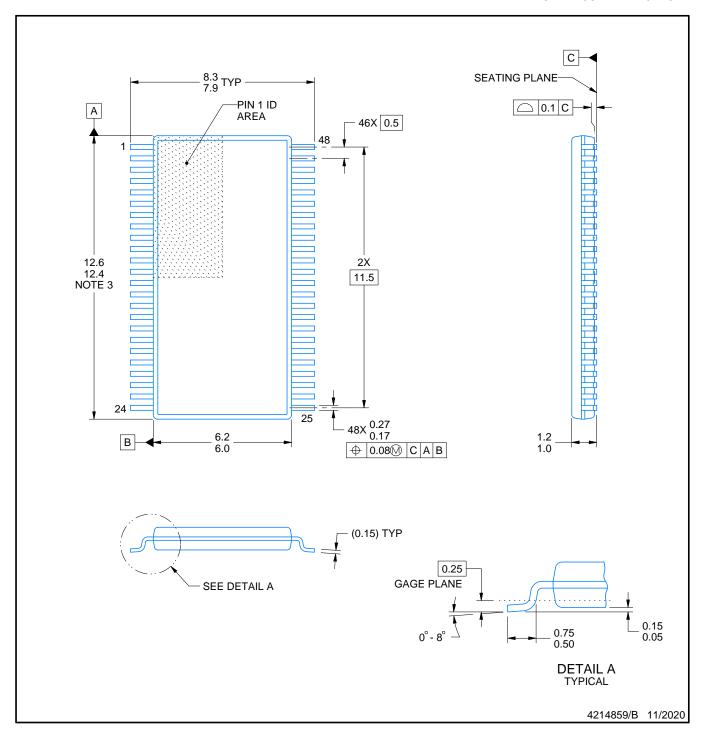


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN65LVDS95DGG	DGG	TSSOP	48	40	530	11.89	3600	4.9
SN65LVDS95DGG.B	DGG	TSSOP	48	40	530	11.89	3600	4.9
SN65LVDS95DGGG4	DGG	TSSOP	48	40	530	11.89	3600	4.9



SMALL OUTLINE PACKAGE



NOTES:

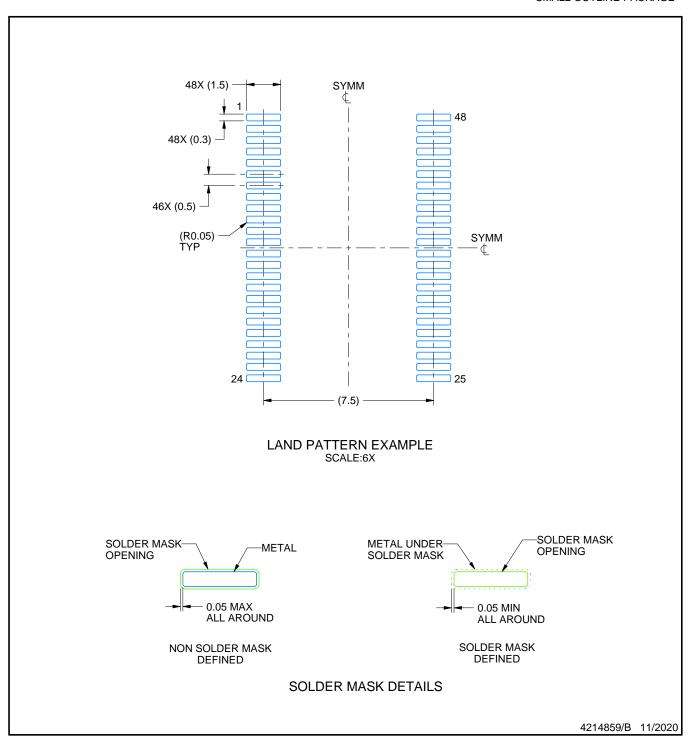
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE

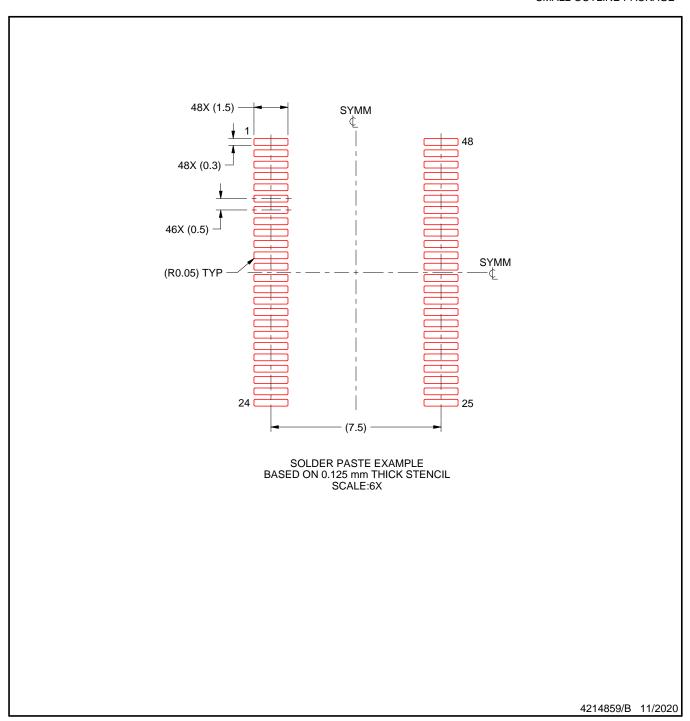


NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

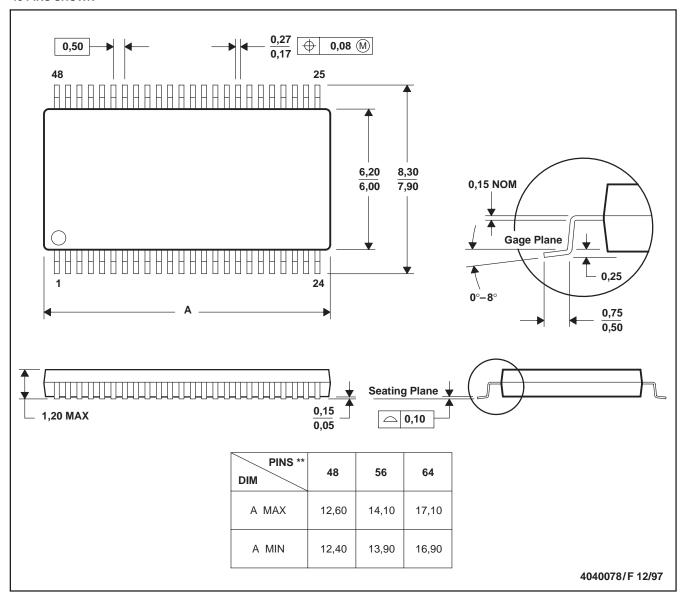
- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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